Reg. No. :

Question Paper Code: 43305

B.E. / B.Tech. DEGREE EXAMINATION, APRIL 2019

Third Semester

Electrical and Electronics Engineering

14UEE305 - SEMICONDUCTOR DEVICES AND CIRCUITS

(Regulation 2014)

Duration: Three hours

Maximum: 100 Marks

Answer ALL Questions

PART A - (10 x 1 = 10 Marks)

1.	The forward current in an PN junction is of

(a) A (b) mA (c) kA (d) μA

- 2. The zero level output from a series clipper circuit is
 - (a) exactly zero (b) exactly one (c) not exactly one (d) not exactly zero
- 3. In optocoupler, which allows a low voltage dc source to control high voltage circuit?
 - (a) output detector(b) electric isolation(c) current transfer ratio(d) output isolation
- 4. Which of the following change is likely to occur in the Q-point when the collector current increases?
 - (a) no change(b) shifts to saturation region(c) shifts to cut-off region(d) oscillates in the active region

5.	n-channel	FETs are	superior to	p-channel	FETs because
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- (a) they have lower switching time
- (b) they have lower pinch off voltage
- (c) mobility of charge carrier electron in n-channel FET is greater than the mobility of charge carrier hole in p-channel FET
- (d) they have higher input impedance
- 6. The dynamic drain resistance of MOSFET is of the order of

(a) 10 *K*Ω (b) 500 *K*Ω (c) $5 M\Omega$ (d) 100 $M\Omega$

In Colpitts oscillator, the amplifier voltage gain usually has to be substantially larger than 7.

	(a) <i>C</i> 2	(b) <i>C1</i>	(c) <i>C1/C2</i>	(d) <i>C2/C1</i>
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- The amplitude stabilizes itself for which the loop gain for the fundamental is reduced to 8. (c) both a and b (d) none of these
 - (a) zero (b) unity
- 9. In UJT, a 3-mil aluminum wire called the
 - (a) base B (b) emitter *E* (c) base *B1* & *B2* (d) all of these

10. A circuit that adds positive or negative DC voltage to an input sine wave is called

(a) clamper (b) clipper (c) diode clamp (d) limiter

PART - B ($5 \times 2 = 10$ Marks)

- 11. List some disadvantages of half wave rectifier.
- 12. Give the relationship between α and β .
- 13. Draw the block diagram of multistage amplifier with *n* number of stages.
- 14. State the condition to produce oscillation.
- 15. State the applications of Schmitt trigger.

PART - C (5 x
$$16 = 80$$
 Marks)

16. (a) With neat diagram explain shunt and series regulators.

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(16)

- (b) Draw the circuit diagram of Full wave rectifier and explain its operation with necessary waveforms. Also derive the expression for rectification, efficiency and transformer utilization factor. (16)
- 17. (a) Describe the input and output characteristics of a transistor in Common Emitter (CE) configuration and also derive its current relation. (16)

Or

- (b) Discuss in detail the analysis of BJT amplifier using h-parameters. (16)
- 18. (a) (i) Derive the expression for output impedance and voltage gain for a common drain amplifier circuit. (10)
 - (ii) Draw a small signal low frequency model for a FET and explain it. (6)

Or

- (b) Discuss in detail about the fabrication, operation and characteristics of P and N-channel JFET. (16)
- 19. (a) Derive the input resistance and output resistance for voltage series and current series feedback amplifier. (16)

Or

- (b) Draw the circuit diagram of Colpitt oscillator and explain its operation. Obtain the expression for its frequency of oscillation. (16)
- 20. (a) Draw the circuit diagram of a monostable multivibrator and explain its operation with relevant waveforms. (16)

Or

(b) For a certain UJT sweep circuit, the resistance is 20 K while the capacitance is $0.2 \mu F$. The valley potential is 1.5 V when VBB = 15 V. Assuming diode cut in voltage of 0.7 V and intrinsic stand-off ratio as 0.5. Calculate the frequency of oscillations. (16)